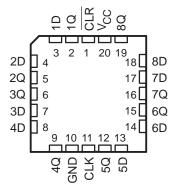
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V<sub>CC</sub>)
- Typical V<sub>OLP</sub> (Output Ground Bounce)
   <0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Support Unregulated Battery Operation Down To 2.7 V
- Buffered Clock and Direct-Clear Inputs
- Individual Data Input to Each Flip-Flop

SN54LVTH273 . . . J PACKAGE SN74LVTH273 . . . DB, DW, NS, OR PW PACKAGE (TOP VIEW)

			_
CLR	1	$\bigcup_{20}$	v <sub>cc</sub>
1Q	2	19	] 8Q
1D	<b>[</b> ]3	18	] 8D
2D	[] 4	17	] 7D
2Q	[ 5	16	] 7Q
3Q	6	15	] 6Q
3D	[]7	14	] 6D
4D	8	13	] 5D
4Q	9	12	] 5Q
GND	10	11	CLK

- I<sub>off</sub> Supports Partial-Power-Down-Mode Operation
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)

SN54LVTH273 . . . FK PACKAGE (TOP VIEW)



## description/ordering information

These octal D-type flip-flops are designed specifically for low-voltage (3.3-V)  $V_{CC}$  operation, but with the capability to provide a TTL interface to a 5-V system environment.

The 'LVTH273 devices are positive-edge-triggered flip-flops with a direct-clear input. Information at the data (D) inputs meeting the setup-time requirements is transferred to the Q outputs on the positive-going edge of the clock pulse. Clock triggering occurs at a particular voltage level and is not directly related to the transition time of the positive-going pulse. When the clock (CLK) input is at either the high or low level, the D-input signal has no effect at the output.

## ORDERING INFORMATION

TA	PACK	AGET	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	COIC DW	Tube	SN74LVTH273DW	1.\/T.1070
	SOIC - DW	Tape and reel	SN74LVTH273DWR	LVTH273
4000 1- 0500	SOP - NS	Tape and reel SN74LVTH273NSR		LVTH273
-40°C to 85°C	SSOP – DB	Tape and reel	SN74LVTH273DBR	LXH273
	TOOOD DW	Tube	SN74LVTH273PW	1.7/1070
	TSSOP – PW	Tape and reel	SN74LVTH273PWR	LXH273
5500 to 40500	CDIP – J	Tube	SNJ54LVTH273J	SNJ54LVTH273J
_55°C to 125°C	LCCC – FK	Tube	SNJ54LVTH273FK	SNJ54LVTH273FK

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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# description/ordering information (continued)

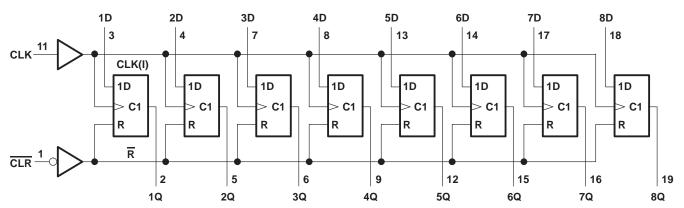
Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

These devices are fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down.

FUNCTION TABLE (each flip-flop)

	INPUTS	OUTPUT	
CLR	CLK	D	Q
L	Х	Χ	L
Н	$\uparrow$	Н	Н
Н	$\uparrow$	L	L
Н	H or L	Χ	$Q_0$

# logic diagram (positive logic)



# absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>	–0.5 V to 4.6 V
Input voltage range, V <sub>I</sub> (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the power-off state, V <sub>O</sub> (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high state, V <sub>O</sub> (see Note 1)	. –0.5 V to $V_{CC}$ + 0.5 V
Current into any output in the low state, IO: SN54LVTH273	96 mA
SN74LVTH273	128 mA
Current into any output in the high state, IO (see Note 2): SN54LVTH273	48 mA
SN74LVTH273	64 mA
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)	–50 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	–50 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 3): DB package	70°C/W
DW package	58°C/W
NS package	
PW package	83°C/W
Storage temperature range, T <sub>stg</sub>	$-65^{\circ}$ C to $150^{\circ}$ C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

- 2. This current flows only when the output is in the high state and  $V_O > V_{CC}$ .
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.

## recommended operating conditions (see Note 4)

		SN54LV	TH273	SN74LV	TH273	
		MIN	MAX	MIN	MAX	UNIT
Vcc	Supply voltage	2.7	3.6	2.7	3.6	V
VIH	High-level input voltage	2	EM	2		V
V <sub>IL</sub>	Low-level input voltage		0.8		0.8	V
VI	Input voltage	4	5.5		5.5	V
IOH	High-level output current	(د)	-24		-32	mA
lOL	Low-level output current	$\gamma_{Q_{\zeta}}$	48		64	mA
Δt/Δν	Input transition rise or fall rate	) <sub>Y</sub>	10		10	ns/V
TA	Operating free-air temperature	-55	125	-40	85	°C

NOTE 4: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

# SN54LVTH273, SN74LVTH273 3.3-V ABT OCTAL D-TYPE FLIP-FLOPS WITH CLEAR

SCBS136M - MAY 1992 - REVISED OCTOBER 2003

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

				SN	54LVTH:	273	SN'	74LVTH2	273	
PAI	RAMETER	TEST CO	ONDITIONS	MIN	TYP	MAX	MIN	TYP†	MAX	UNIT
VIK		V <sub>CC</sub> = 2.7 V,	I <sub>I</sub> = -18 mA			-1.2			-1.2	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V},$	I <sub>OH</sub> = -100 μA	V <sub>CC</sub> -0	.2		V <sub>CC</sub> -0	.2		
		$V_{CC} = 2.7 \text{ V},$	$I_{OH} = -8 \text{ mA}$	2.4			2.4			
VOH		V 2 V	I <sub>OH</sub> = -24 mA	2						V
		V <sub>CC</sub> = 3 V	$I_{OH} = -32 \text{ mA}$				2			
		V 07V	I <sub>OL</sub> = 100 μA			0.2			0.2	
		V <sub>CC</sub> = 2.7 V	I <sub>OL</sub> = 24 mA			0.5			0.5	
\/ - ·			I <sub>OL</sub> = 16 mA			0.4			0.4	.,
$V_{OL}$		V 2.V	I <sub>OL</sub> = 32 mA			0.5			0.5	V
		V <sub>CC</sub> = 3 V	$I_{OL} = 48 \text{ mA}$		0.55					
			$I_{OL} = 64 \text{ mA}$		0-				0.55	
		$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V <sub>I</sub> = 5.5 V		7	10			10	
6.	Control inputs	$V_{CC} = 3.6 \text{ V},$	$V_I = V_{CC}$ or GND		5	±1			±1	^
l <sub>l</sub>	Data innuta	V 26V	$V_I = V_{CC}$		5	1			1	μΑ
	Data inputs	V <sub>CC</sub> = 3.6 V	V <sub>I</sub> = 0	Q	7	-5			-5	
l <sub>off</sub>		$V_{CC} = 0$ ,	$V_I$ or $V_O = 0$ to 4.5 $V$						±100	μΑ
		V 2.V	V <sub>I</sub> = 0.8 V	75			75			
11/15 = 1 = 1	Data inputs	VCC = 3 V	V <sub>I</sub> = 2 V	-75			-75			μΑ
l(hold)	Data inputs	V <sub>CC</sub> = 3.6 V <sup>‡</sup> ,	V <sub>I</sub> = 0 to 3.6 V						500 -750	μΑ
		$V_{CC} = 3.6 \text{ V}, I_{O} = 0,$	Outputs high			0.19			0.19	^
ICC		$V_I = V_{CC}$ or GND	Outputs low			5			5	mA
Δlcc§		$V_{CC} = 3 \text{ V to } 3.6 \text{ V, One}$ Other inputs at $V_{CC}$ or 0	e input at V <sub>CC</sub> – 0.6 V, GND			0.2			0.2	mA
Ci		V <sub>I</sub> = 3 V or 0			4			4		pF

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

# timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

				SN54L\	/TH273			SN74L\	/TH273		
			V <sub>CC</sub> =		VCC =	2.7 V	V <sub>CC</sub> =	3.3 V 3 V	VCC =	2.7 V	UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
fclock	Clock frequency			150				150			MHz
t <sub>W</sub>	Pulse duration		3.3		3.3		3.3		3.3		ns
	:	Data high or low before CLK↑	2.3	00°	2.7		2.3		2.7		
t <sub>su</sub>	Setup time CLR high before CLK↑		2.3	6,66	2.7		2.3		2.7		ns
th Hold time, data high or low after CLK↑			0		0		0		0		ns



<sup>&</sup>lt;sup>‡</sup> This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

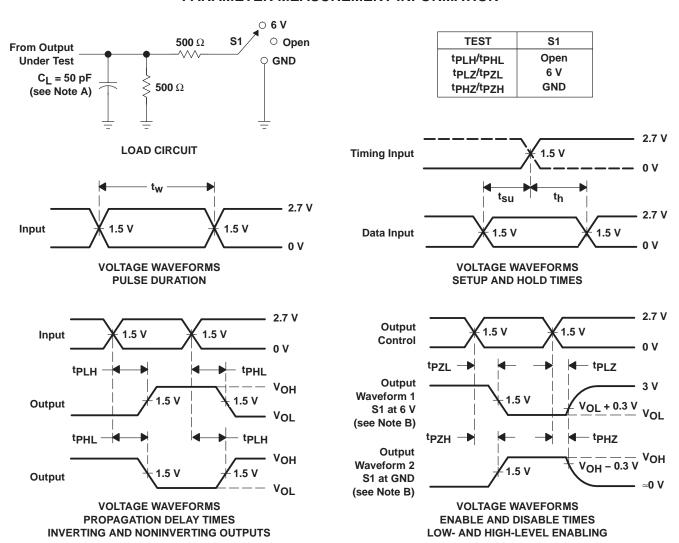
<sup>§</sup> This is the increase in supply current for each input that is at the specified TTL voltage level, rather than VCC or GND.

# switching characteristics over recommended operating free-air temperature range, $C_L = 50$ pF (unless otherwise noted) (see Figure 1)

				SN54L\	/TH273			SN7	4LVTH2	273		
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3.3 V ± 0.3 V			V <sub>CC</sub> = 2.7 V		UNIT
			MIN	MAX	MIN	MAX	MIN	TYP†	MAX	MIN	MAX	
f <sub>max</sub>			150		Á		150					MHz
t <sub>PLH</sub>	OLK.	A O	1.6	5	1000	5.6	1.7	3.2	4.9		5.5	
<sup>t</sup> PHL	CLK	Any Q	1.8	4.9	7	5.2	1.9	3.2	4.8		5.1	ns
<sup>t</sup> PHL	CLR	Any Q	1.5	4.4		4.8	1.6	2.7	4.3		4.7	ns

 $<sup>\</sup>dagger$  All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C.

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>I</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \ \Omega$ ,  $t_f \leq 2.5 \ ns$ .
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN74LVTH273DBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH273	Samples
SN74LVTH273DW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH273	Samples
SN74LVTH273DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH273	Samples
SN74LVTH273DWRE4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH273	Samples
SN74LVTH273DWRG4	ACTIVE	SOIC	DW	20	2000	TBD	Call TI	Call TI	-40 to 85		Samples
SN74LVTH273NSR	ACTIVE	SO	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH273	Samples
SN74LVTH273PW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH273	Samples
SN74LVTH273PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	LXH273	Samples
SN74LVTH273PWRG4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH273	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

# **PACKAGE OPTION ADDENDUM**

www.ti.com 13-Jul-2022

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF SN74LVTH273:

■ Enhanced Product : SN74LVTH273-EP

NOTE: Qualified Version Definitions:

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 3-Jun-2022

# TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVTH273DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LVTH273DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74LVTH273NSR	so	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74LVTH273PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74LVTH273PWRG4	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1



www.ti.com 3-Jun-2022



#### \*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVTH273DBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74LVTH273DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LVTH273NSR	so	NS	20	2000	367.0	367.0	45.0
SN74LVTH273PWR	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74LVTH273PWRG4	TSSOP	PW	20	2000	356.0	356.0	35.0

# **PACKAGE MATERIALS INFORMATION**

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# **TUBE**



## \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74LVTH273DW	DW	SOIC	20	25	507	12.83	5080	6.6
SN74LVTH273PW	PW	TSSOP	20	70	530	10.2	3600	3.5





- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# PW (R-PDSO-G20)

# PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
  C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# **MECHANICAL DATA**

# NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

# PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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